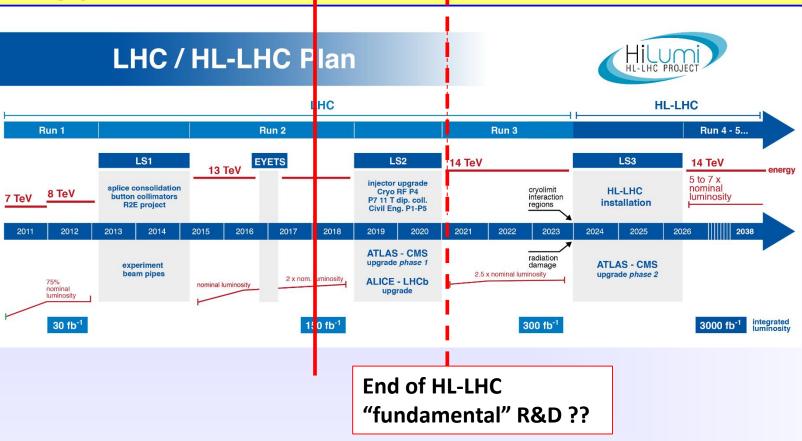
Future R&D



Future R&D





• Shifting RD target?

Today, this morning!



Future work on FCC tracking



 VERTEX Conference September 2017: Status & Challenges of Tracker Design for FCC-hh, Zbyněk Drásal on behalf of FCC-hh detector working group

Summary & Challenges

- The key tracker parameters have been studied & optimized:
 - → Layout: ~430m² (391m² in tilted layout) of Si, with: 5461M (pixels), 9964M (macropixels), 489M (strips)
 - → The granularity in R-Φ driven mostly by dp₋/p₋ @p₋=10TeV/c → achieved dp₋/p₋ ~20%
 - → The granularity in Z driven by prim. vertexing & pattern recognition capabilities @PU=1000:
 - Due to minimized mat. budget the tracker (even vertex detector) in tilted layout very advantageous to achieve similar pattern recognition performance as with PU~140 & HL-LHC conditions
 → realistic engineering (technology input) with services, cooling & support structure important!
 - Primary vertexing & correct PV assignment @PU=1000 seems feasible up-to η~4, but only
 with precise timing information σ_t~5ps (2D vertexing, several timing layers assumed) → the limiting
 factor for high η coverage is beam-pipe material
 - → Expected data rates (**766 TB**/s **untriggered**, **19 TB**/s **triggered** @**1MHz**) implicate need for new read-out technologies (high speed, low power optical links) & dedicated trigger design!
 - → 1MeV neq fluence ~6x10¹⁷cm⁻² & TID ~0.4GGy @ R=25mm represent new challenges for the tracker (vertex detector) technologies
 - → Dedicated R&D is needed to meet the challenging requirements!



Z.Drásal, Vertex 2017 Asturias Spain (10-15th September 2017)

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Sensor/Frontend Electronics point of view: Showstoppers!!

Need for radhard precise timing detectors 5ps:

→ Not existing!

...so far 30ps seems feasible.

Need for ultra-radhard detectors

— Present detectors will not work at
6e17 neq/cm2 → Not existing!

Note: We not even understand the solid
state physics in devices irradiated to this
level of fluence.

Exploit new technologies, reduce radiation length, reduce complexity (i.e. increase integration) ... go monolithic.

....note that RD50 is already working on many of the challenges (next slides)



RD50 Workplan for 2017/2018 (1/2)



Understand the Physics of radiation damage

- **Defect and Material Characterization** (Convener: Ioana Pintilie, Bucharest)
- Consolidate list of defects and their impact or sensor properties (Input to simulation group) including introduction rates & annealing for different type of irradiations and materials
- Extend work on p-type silicon including low resistivity material
 - Understand boron removal in lower resistivity p-type silicon:
 Performance of MAPS, CMOS sensors, LGAD ... adding new macroscopic measurements
 - Working group on acceptor removal formed!
- Characterization of Nitrogen enriched silicon (starting project, wafers ready)
- **Detector Characterization** (Copy
- TCAD sensor simulations

Provide the tools to characterize and predict damage and optimize devices for performance

- Cross-calibration of different simulation tools (ongoing) and comparison of "TCAD models"
- Refine defect parameters used for modeling (from effective to measured defects)
- Extend modeling on charge multiplication processes
- Surface damage working group
- Extend use of signal simulation tools towards fitting of measured data
- Extend experimental capacities on e-TCT equipment
 - Parameterization of electric field (fluence, annealing time, etc.)
- Exploit full potential of Two Photon Absorption for sensor characterization; build setup at CERN
- Continue parameterization of radiation damage (performance degradation) of LHC like sensors !
- Explore fluence range to10¹⁷cm⁻²and beyond (to prepare for future needs in forward physics and FCC)



RD50 Workplan for 2017/2018 (2/2)



- **New structures** (Convener: Giulio Pellegrini, CNM Barcelona, Spain)
 - Continue work on thin and 3D sensors (especially in combination with high fluence)
 - Continue characterization of dodicated avalanche test structures (ICAD_DD_ADD)
 - Understand impact of impl

Provide precision timing detectors

esses

- Study of Gallium based amplification layers and impact of Carbon co-implantation
- LGAD, DD-APD: intensify evaluation of timing performance and radiation degradation
 (Where are the limits? How to overcome radiation damage? How much gain is optimum?)
- HVCMOS

Go monolithic

- Continue characterization of existing devices (close collaboration with ATLAS HVCMOS group)
- End of year: submission of first RD50 devices in an engineering run
- Full detector systems (Convener: G.Kramberger, Ljubljana University, Slovenia)
 - Further studies of thin (low mass) segmented silicon devices
 - Study performance of thin and avalanche sensors in the time domain (Fast sensors!)
 - Long term annealing of segmented sensors (parameterize temperature scaling)
 - Continue study on "mixed" irradiations (segmented detectors)
 - ▼ Continue RD50 program on slim edges ada paccivation and active adaptive

Keep close link with the Experiments

(both: in planning/preparation and in operation)

- Merging of RD39 into RD50
 - Cryogenic operation at high fluences?
- Links with LHC experiments and their upgrade working groups
 - <u>Continue</u> collaboration on evaluation of radiation damage in LHC detectors
 - Continue common projects with LHC experiments on detector developments



European Strategy



GLOBAL PARTICLE PHYSICS STRATEGY

Japan: Future HEP Projects

 - "... Japan should take the leadership role in an early realisation of an e+e- linear collider." ICFA (International Committee for Future Accelerators)

Update of European Strategy for by CERN Council (May 2013)

- LHC, incl. HL-LHC
- accelerator R&D
- strong support for ILC
- long-baseline neutrino
- importance of theory



- Different flavours in different regions of the world
- > But looks like an emerging global, coherent strategy in particle physics
- Next update of European strategy 2020; US to follow 2-3 years after.

USA: Snowmass conclusions and recommendations to P5 in line with worldwide strategy statements

